

KSA910

Driver Stage Of Audio Amplifier & High Voltage Switching Applications

Collector-Emitter Voltage: V_{CEO}= -150V
Output Capacitance: C_{ob}=5pF (MAX.)
Complement to KSC2310



1. Emitter 2. Collector 3. Base

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage	-150	V
V _{CEO}	Collector-Emitter Voltage	-150	V
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current	-50	mA
P _C	Collector Power Dissipation	800	mW
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = -100 \mu A, I_E = 0$	-150			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = -5mA$, $I_B = 0$	-150			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = -10\mu A, I_C = 0$	-5			V
I _{CBO}	Collector Cut-off Current	V _{CB} = -150V, I _E =0			-100	nA
h _{FE}	DC Current Gain	V_{CE} = -5V, I_{C} = -10mA	40		240	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I_C = -10mA, I_B = -1mA			-0.8	V
f _T	Current Gain Bandwidth Product	V_{CE} = -30V, I_{C} = -10mA		100		MHz
C _{ob}	Output Capacitance	V _{CB} = -10V, I _E =0, f=1MHz			5	pF

h_{FE} Classification

Classification	R	0	Y
h _{FE}	40 ~ 80	70 ~ 140	120 ~ 240

Typical Characteristics

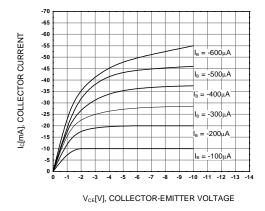


Figure 1. Static Characteristic

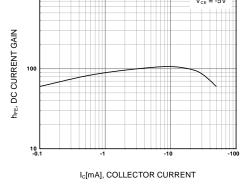


Figure 2. DC current Gain

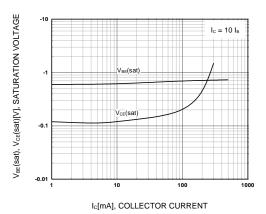


Figure 3. Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage

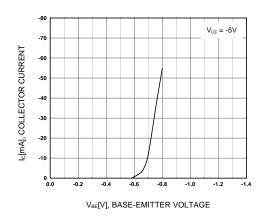


Figure 4. Base-Emitter On Voltage

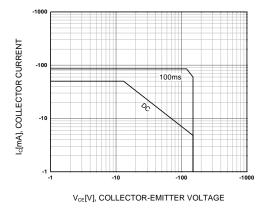


Figure 5. Safe Operating Area

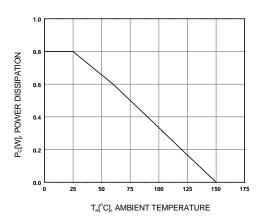
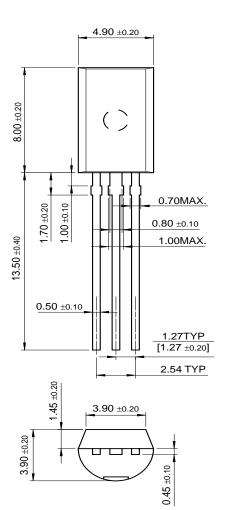


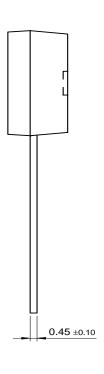
Figure 6. Power Derating

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Package Demensions

TO-92L





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